



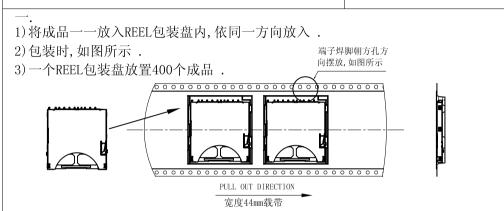
RTOM® 深圳市愛特姆科技有限公司

SHENZHEN ATOM TECHNOLOGY CO., LTD.

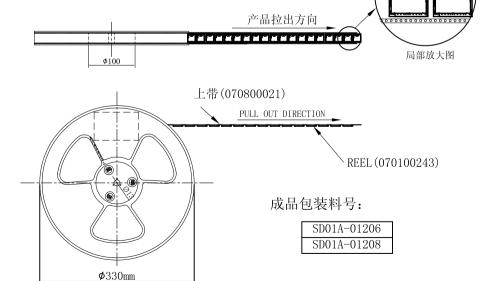
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文件名称

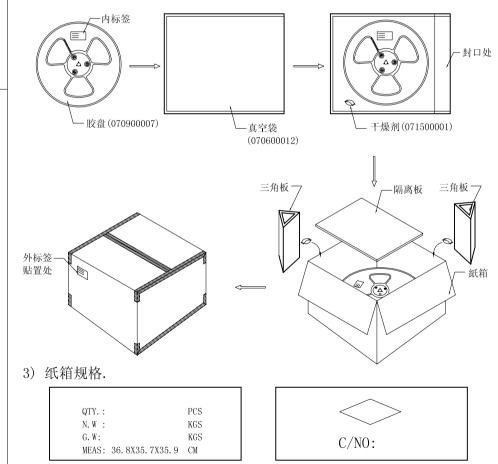
SD CARD PUSH-PUSH 接地片外焊(带假卡)卷带包装规范



- 1)装盘前先把前面空300mm,然后再开始装盘,尾端也 需空出300mm, 目将上带空出100mm。
- 2)装满成品的REEL包装盘如下图所示。



- 1)每盘产品贴一张内标签,然后将胶盘放入真空包装袋,袋内放一包干燥剂, 再使用真空包装机抽气封口.
- 2) 纸箱上下各放一块隔离板,将每盘产品依次放入箱内,一箱装7盘,四周用三角板 固定,每箱内放二包干燥剂,最后用透明胶纸将纸箱四周封实,箱外贴上外标签,
- 3) 若有未装满之零数箱, 必须以缓行材料塞满, 数量比较少时可单盘包装出货,



核准

杨和敏

审核

李建胜

制定

鲜慧

发行编号

07



- 1. Scope: This specification covers the requirements for product performance and test methods of SD CARD CONNECTOR. This SD Card has low profile as well as Push-push function t's suitable for digital product. Such as camera, Notebook, smart phone...
- 2. Product Shape, Dimensions and Material: Refer to the drawing.
- 3. Ratings:

Item	Dimensions
Rated Current(Max)	0.5A AC(rms)/DC
Rated Voltage(Max)	100V AC/DC
Operating Temperature Range	-25 ~90
Storage Temperature Range	-40 ~90
Operating Humidity Range	95% R.H. MAX

4. Performance:

4.1. Electrical Performance

Test Ref.	Item	Test Condition	Standard
4.1.1	Contact	Mate dummy card, measure contact resistance	100mΩ ΜΑΧ
	Resistance	Using the four terminals method as shown in	
		Fig1.Apply the low level condition of DC20mV	
		MAX. For the open circuit voltage and DC10mA	
		MAX. for the closed circuit current, in accordance	
		with EIA-364-23.	
4.1.2	Insulation	Apply DC250V between the neighboring contacts	1000MΩ MIN
	Resistance	or contact and ground, in accordance with	
		EIA-364-21.	
4.1.3	Withstanding	Apply AC500V (rms) between the neighboring	Without damage
	Voltage	contacts or contact and shell for a minute ,in	such as arcing or
		accordance with	breakdown etc.
		EIA-364-20.	
4.1.4	Temperature	Mate dummy card, and attach a thermo couple to	30 MAX
	Rise	the soldering part, then apply the rating amperage.	
		Equilibrium temperature shall be measured by a	
		thermo couple measuring method,	
		in accordance with	
		EIA-364-70.	

Product Description SD CARD PUSH-PUSH TYPE		Product NO:			
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4.2 Mechanical Performance:

Test Ref.	It	em		Test Condition		Stand	ard
4.2.1	Contact Retention Force		opposite to the	n the contact alone the e contact insertion at a Measure the force wheen	0.15kgf MI	N.	
4.2.2	Card In Force	sertion	Push the actual 25±3mm/min.	lly card at the speed r	ate of	Insertion Fo 2.00Kgf MA	
4.2.3	Card Re Force	etention	Insert the SD of card at 25±3m	card in right position a m/min.speed.	and then pull the	Initial: 0.20kgf MII After operat cycles: 0.15	ed 10000
4.2.4	Card di	rection		1. Normal The actually card is inserted in a positive direction and the load of 5kgf is added for ten seconds.			e] ility istance
			positive direct	or behind The SD card ion of the back and a f 3kgf is added for ter	[Appearance No abnorma [Contact Re Shall meet 4	sistance]	
				s inserted backward as added for ten second	[Appearance No abnorma [Contact Re Shall meet 4	llity sistance]	
4.2.5	durabili	ty	Insertion and extraction are repeated 10000 cycles with the actually card at the speed rate of 400-600 cycles/h in accordance with EIA-364-20.			[Appearance No abnorma [Contact Re Shall meet 4	sistance]
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4.3 Environmental Performance and Other

Test Ref.	Item	Test Condition	Standard
4.3.1	Humidity	Mate dummy card and expose them to the	[Appearance]
	(Steady State)	following environment in accordance with	No abnormality
		EIA-364-31, Method III,.	[Contact Resistance]
		Temperature: 40 ± 2	Shall meet 4.1.1.
		Humidity: 90~95%RH	[Insulation
		Duration: 96hours	Resistance]Shall meet
		Recovery time 1~2 hours	4.1.2.
			[Dielectric Withstanding
			Voltage] Shall meet
			4.1.3.
4.3.2	Shock	Mate dummy card and place them on the shock	[Appearance]
		machine, then apply the following shock. Then it	No abnormality
		shall be measured. In accordance with	[Contact Resistance]
		EIA-364-27	Shall meet 4.1.1.
		Max. G: 50G	[Insulation Resistance]
		Standard duration: 11msec.	Shall meet 4.1.2.
		Wave form: Half sinusoidal	[Dielectric
		Test times: 3 times for each direction, total	Withstanding Voltage]
		of 18 times.	Shall meet
			4.1.3.[Discontinuity
			greater]1.0µsMAX.
4.3.3	temperature	Mate dummy card and subject to the following	[Appearance]
	(Cycling)	condition for 5 cycles . Upon completion of the	No abnormality
		exposure period ,the test specimens shall be	[Contact Resistance]
		conditioned at ambient room conditions for 1 to 2	Shall meet 4.1.1.
		hours after which the specified	
		Measurements shall be performed.	
		1 cycle a) -55±330 minutes	
		b) +85±230 minutes	
		Transit time shall be within 3 minutes.	

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		PRODUCT SPECIFICATION	N
4.3.4	Vibration	Mate dummy card and place them on the	[Appearance]
		vibrator, hen apply the following vibration. Hen it	No abnormality
		shall be measured. In accordance with EIA-364-28	[Contact Resistance]
		Frequency: 10Hz ~55Hz ~10Hz/1min.	Shall meet 4.1.1.
		Direction: Three mutually perpendicular	[Insulation Resistance]
		Directions .Total amplitude: 1.52mm Sweep	Shall meet 4.1.2.
		duration: 2 hours for each direction, a total of 6	[Dielectric Withstanding
		hours.	Voltage] Shall meet
			4.1.3 [Discontinuity
			greater]1.0µs MAX.
4.3.5	High	Mate dummy card and expose them to the	[Appearance]
	Temperature	following environment in accordance with	No abnormality
	Life	MIL-STD-202F,Method108A ,Condition C.	[Contact Resistance]
		Temperature: $+85 \pm 2$	Shall meet 4.1.1.
		Duration: 96 hours	
4.3.6	Cold	Mate dummy card and expose them to the	[Appearance]
	Temperature	following environment.	No abnormality
	Life	Temperature: -40 ± 3	[Contact Resistance]
		Duration : 96 hours	Shall meet 4.1.1.
4.3.7	Thermal Shock	Mate dummy card and expose them to the	Appearance
		following environment in accordance with	No abnormality
		MIL-STD-202F, Method108, Condition C.	Contact Resistance
		Temperature:-25 :30min. 60 :30min	Shall meet 4.1.1.
		Transition time: 5min.MAX	
		No. of cycles: 5 cycles	
4.3.8	Salt Water	35 ± 2 \ $5 \pm 1\%$ salt spray	Appearance
	Spray	1. Sn plated area at least 12 hours	No abnormality
		2. Au plated area 1-3u" for at least 24 hours	Contact Resistance
		3. Au plated area 5u" for at least 48 hours	Shall meet 4.1.1.
		Clean by normal-temperature water after test and	
		then dry under room temperature.	

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		TROBECT SILENTENTION	
Test Ref.	Item	Test Condition	Standard
4.3.9	Solderability	Dip the solder tine of the contacts in the solder bath at 518±5K (240±5) for 5±0.5seconds after immersing the tine in the flux of RMA type for 5 to 10 seconds in accordance with EIA-364-52 Category 2.	More then 95% of the dipped surface shall be wet and less than 5% of the pinhole that shall not gather at a point.
4.3.10	Soldering Heat Resistance	1). Reflow part 260±5 Peak 220 MIN. 60sec.MAX. 2). Pre-heat part 180 , 0~120sec. * Refer to reflow temperature profile. * The number of reflow is within 2 times. 265 MAX. (Peak temperature) Average range up:1.8 /s MAX 40-60 秒 40-60sec. 90-120 秒 90-120 sec (220 MIN.) (220 以上) (预热 150 180) (Pre-heat 150 180)	No abnormality adversely affecting the performance shall not occur.

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